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1. Introduction

Low cost solar power harvesting on a massive scale is a challenge which has led to the development of new photovoltaic technologies that pave the way for affordable renewable energy. One of the leading solar cell candidates is the dye sensitized solar cell (DSSC).¹⁻³ DSSCs based on nanocrystalline TiO₂ photoanodes have been regarded as one of the most promising alternatives to conventional solar cells due to their low cost, ease of fabrication, environmentally friendly nature and flexibility of design in view of their colors and transparencies and relatively high power conversion efficiencies (PCEs). These features make DSSCs the ideal photovoltaic devices for commercial applications,^{4,5} and extensive research has been devoted to the development of high performance DSSCs.⁶ The usage of a mesoporous $TiO₂$ n-type semiconductor electrode in DSSCs as a photoanode of high internal surface area has led to

Hydrothermal synthesis of $TiO₂$ nanoparticles doped with trace amounts of strontium, and their application as working electrodes for dye sensitized solar cells: tunable electrical properties & enhanced photo-conversion performance†

Hadja Fatima Mehnane, Changlei Wang, Kiran Kumar Kondamareddy, Wenjing Yu, Weiwei Sun, Haimin Liu, Sihang Bai, Wei Liu,* Shishang Guo* and Xing-Zhong Zhao*

Strontium (Sr) doped $TiO₂$ nanoparticles are investigated with a view to studying the performance parameters of dye sensitized solar cells (DSSCs). Sr is used in trace levels (parts per million, ppm hereafter). The Sr doped TiO₂ and undoped TiO₂ nanoparticles are synthesized by the hydrothermal method and thin films of TiO₂ electrodes are prepared using these particles (average grain size of 24 nm). The electrodes are characterized by X-ray diffraction (XRD), Scanning Electron Microscopy (SEM), surface area (BET) and UV-vis absorption spectrometry. DSSCs are fabricated using the doped and undoped TiO₂ nanoparticle photoanodes. Their photovoltaic characteristics are studied by employing J-V measurements and electrochemical impedance spectroscopy (EIS). XRD studies reveal that the doping of Sr into the TiO₂ lattice slightly inhibits the growth of the particles and causes lattice distortions. The optical studies indicate a reduction in band-gap upon doping of TiO₂ films and a simultaneous enhancement in the photocurrent density (J_{sc}) and the photovoltage (V_{oc}) . The photoanode doped with 50 ppm Sr exhibits the highest power conversion efficiency (PCE) of about 7.88% which is 12.73% higher than that of undoped $TiO₂$ cells. The effect of the Sr dopant on electron transport is studied by using EIS measurements. An improvement in electron life time is observed on the doping of TiO₂. PAPER

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a step change in the fields of photoelectrochemistry and photovoltaics. For state-of-the-art DSSCs, the architecture of the mesoporous $TiO₂$ electrode in the devices has seen much improvement since 1991, in terms of light absorption, light scattering, charge transport, suppression of charge recombination and alteration of the interfacial energetics.⁵ TiO₂ is still the most successfully used wide band gap oxide material among other wide band semiconductor oxides such as ZnO , $SnO₂$, $Nb₂O₅$ and SrTiO₃, due to its stability, non-toxicity and highly refractive nature.⁷ Therefore the development of advanced photovoltaic anode materials that effectively utilize solar energy from the visible region is an appealing challenge, particularly for DSSC applications, as the light absorption and charge collection take place at the dye sensitized mesoporous photoanode.8,9 One of the effective ways to tailor the electronic properties of $TiO₂$ photoanodes is by deliberately inserting impurities into the $TiO₂$ lattice.¹⁰ Such doping is also important in improving the performance of other kinds of mesoscopic solar cells.^{11,12} Doping of DSCCs with TiO₂ is expected to control the morphology of the $TiO₂$ with the prospect of maximizing both the dye/TiO₂ interface area and the light absorption.^{13,14}

Metallic¹⁵⁻¹⁷ and non-metallic elements^{18,19} are used in doping of TiO₂ photoanodes. Doping by rare earth and

School of Physics and Technology, Key Laboratory of Artificial Micro/Nano Structures of Ministry of Education, Wuhan University, Wuhan 430072, China. E-mail: xzzhao@ whu.edu.cn; gssyhx@whu.edu.cn; wliu@whu.edu.cn

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The pure and Sr doped $TiO₂$ pastes were prepared using the hydrothermal method as described elsewhere.¹⁸ In a typical synthesis process, 2.1 g of acetic acid was dispersed into 10 ml of titanium isopropoxide (TTIP) using ultrasonic mixing for 10 min and the dispersion was then quickly dropped into 50 ml of deionized water under stirring to start the hydrolysis reaction. After 1 hour, Sr precursors of various trace concentrations (molar ratios: 20 ppm, 50 ppm, 80 ppm) were added to TTIP hydrolyzed solutions to prepare doped $TiO₂$ samples (and an undoped TiO₂ sample was also prepared). The hydrolysis was continued under vigorous stirring for 3 h at room temperature. Then 0.68 ml of nitric acid was added to each resultant precursor solution under continuous stirring. The temperature was maintained at a constant 80 \degree C for 4 h to obtain transparent solutions which were then filtered to wipe off insoluble impurities. The volume of each solution was adjusted to 68 ml by adding deionized water and each sample was then heated at 220 °C in a 100 ml autoclave for 12 h. After the hydrothermal process 0.4 ml of nitric acid was added to each sol–gel and it was stirred for 5 h. Finally each sol–gel was dispersed ultrasonically. In order to get final pure and Sr doped $TiO₂$ nanoparticles, the dispersed sol–gels were centrifuged and then dispersed in ethanol, ethyl cellulose and terpineol successively after proper drying. The mixtures were pulverized in an agate vial using a ball mill (QM-3SP2) for 12 h and sonicated for 30 min. These steps were alternately repeated three times in order to obtain homogenous solutions. During the pulverization, a plastic deformation of the TiO₂ crystal lattice took place which resulted in stresses and strains that distorted the lattice and formed many defects in the $TiO₂$ particles. Furthermore, the high surface energy and lattice distortion energy facilitated the achievement of the required activation energy for atomic and ionic diffusion at room temperature. The collisions that Paper

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occurred among the grains of powder and the balls of the mixer mill caused a rise in interface temperature which induced the homogeneous incorporation of dopants. After the pulverization, ethanol was removed from the mixtures using rotary evaporation to extract the final pastes of pure and Sr doped $TiO₂$.

2.3. Preparation of the photoelectrodes and different DSSC devices

Films of uniform thickness were obtained by coating the pure and Sr doped TiO₂ pastes onto the FTO using the doctor-blade method. The films were dried on a hotplate at 125 \degree C and then sintered for 30 min at 500 $^{\circ}$ C in an oven to obtain the mesoporous electrodes. A TiO₂ scattering layer²⁶ was added to each electrode using the doctor blade method, and this was followed by annealing at 500 $^{\circ}$ C for 30 min. The pre-heated $(125 \degree C)$ for 30 min) mesoporous electrodes were then immersed in 0.5 mM ethanolic N719 solution at room temperature for 24 h and were washed with ethanol to remove the excess dye molecules. After ensuring that the nanocrystalline $TiO₂$ electrodes were covered by a monolayer of dye molecules, the electrodes were dried at $60 °C$ in air. Finally DSSCs were fabricated by sandwiching the electrolyte²⁷ layer between a N719

when they are introduced into $TiO₂$ nanocrystals.¹² Peng et al.²⁰ reported that the substitution of Mg^{2+} ions into the anatase lattice affected its band edge movement and charge recombination and improved the open circuit voltage (V_{oc}) of DSSCs. Liu et al.²¹ demonstrated that Ca doped TiO₂ photoanodes showed a positive shift in flat band potential of $TiO₂$ which caused an increase in efficiency of electron injection and improved electron transport properties. Sr doped TiO₂ electrodes of nanotube arrays were fabricated to improve the photo-conversion efficiency for water splitting applications.²² Sr doped TiO₂ nanoparticles have been employed as photocatalysts where they showed enhanced photocatalytic activity due to their high surface area, improved charge transfer rate at the solid–liquid interface and suppression of electron–hole pair recombination.²³ DSSCs based on TiO₂ nanotube arrays that had been surface treated by strontium oxide (SrO) showed a higher photovoltaic performance.²⁴ However, a study of TiO₂ nanoparticles doped with the alkaline earth element Sr at ppm level concentrations for photoanodes of DSSCs has not previously been reported. Therefore the present investigations are aimed at employing a Sr doped $TiO₂$ photoanode and studying its influence on the photovoltaic performance of DSSCs. For the first time, the authors report on $TiO₂$ nanoparticles doped with trace amounts (several parts per million (ppm)) of Sr for DSSC applications. The photoanodes were prepared by the hydrothermal method and characterized by X-ray diffraction (XRD), scanning electron microscopy (SEM), and UV-visible absorption spectrometry. The influence of the dopant Sr on the electron transport and recombination processes in the photoanode is monitored by J–V characterisation studies and electrochemical impedance spectroscopy (EIS) measurements. It is found that doping with trace amounts of Sr is effective in enhancing the short circuit current density $(J_{\rm sc})$ and $V_{\rm oc}$ simultaneously which contribute to a significant improvement in the conversion efficiency for DSSCs.

transition metal ions, in particular, are reported by many researchers. However, studies on alkaline earth metal ion doped $TiO₂$ nanoparticles for DSSC photoanode applications, and investigations on their photovoltaic properties have rarely been carried out. The alkaline earth metals are interesting cationic dopants as they might donate s electrons from their outer shells

2. Experimental section

2.1. Materials

Titanium isopropoxide (TTIP, Ti $[OCH(CH_3)_2]_4$) and strontium nitrate $(Sr(NO₃)₂·9H₂O)$ were used as precursors of Ti and Sr respectively. In order to set the concentration of the solutions, following the earlier report, 25 two kinds of ethyl cellulose were employed to prepare an ethanolic mixture. Fluorine doped SnO₂ conductive glass (FTO, sheet resistance 10-15 U sq. $^{-1}$; Asahi Glass, Japan), N719 dye (Solaronix, Switzerland), iodine (12, 99.8%; Beijing Yili chemicals, China); lithium iodide (LiI, 99%), guanidine thiocyanate (GNCS) and 4-tert-butylpyridine (TBP) (Acros); and propylene carbonate (PC; Sinopharm Chemical Reagent Corporation, China) were used as received without any modifications.

dye-loaded photoelectrode and Pt-coated FTO counter electrode. The Pt counter electrode was prepared by the sputtering method while the liquid electrolyte solution was prepared by dissolving 0.05 M LiI (lithium iodide, 99%), 0.03 M I₂ (iodine, 99.8%), 0.01 M PMII (1-methyl-3-propyl imidazolium iodide), 0.1 M GNCS (guanidine thiocyanate) and 0.5 M TBP (4-tertbutylpyridine) into a solvent composed of acetonitrile and PC (volume ratio: 1 : 4).

2.4. Characterization of DSSCs

The actual concentrations of Sr dopant were measured using inductively coupled plasma atomic emission spectroscopy (ICP-AES) [ESI, Table $1\dagger$] which confirmed that the concentrations were in the ppm range, albeit at lower levels than had been added to the precursor solutions. The structural analysis of the pure and Sr doped $TiO₂$ photoanodes was carried out by XRD studies, SEM and UV-vis spectroscopy. XRD patterns of the photoanodes were recorded using a Bruker XRD system (D8 Advanced, Germany) employing Cu Ka radiation. The morphology of the samples was monitored by field emission (FE)-SEM (Sirion, FEG). Specific surface area, pore volume, and pore size diameter were measured using nitrogen adsorption– desorption isotherms at 77 K obtained using a JW-BK122W analyzer (China). The optical absorption spectra were taken in the range of 300–800 nm using UV-vis spectrophotometry (Lambda 650S PerkinElmer). The amounts of dye loaded on the photoanodes were measured from the UV-vis spectra of the dye desorbed from the as prepared photoanodes upon immersion in an aqueous solution of NaOH (0.1 M). X-ray photoelectron spectroscopy (XPS) was carried out on a Thermo Fisher ESCA-LAB 250Xi, employing monochromatic Al Ka radiation (1486.68 eV), an ultrahigh vacuum under CAE mode with a pass energy of 20 eV and a step size of 0.05 eV. The binding energies were calibrated with respect to the carbon (C1s) peak (284.8 eV). Photovoltaic measurements of the devices were performed using a solar simulator CHI660C electrochemical workstation (CH Instruments, Shanghai, China), which provides AM 1.5 G illumination with an equivalent light intensity of 1000 W m^{-2} (under 1 Sun illumination) at room temperature. The irradiated area of each cell was confined to 0.25 cm^2 by using a light tight metal mask. **BSC** Advances Articles. Provide and Procede TrO counter dec-

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3. Results and discussion

XRD patterns of the Sr doped and undoped $TiO₂$ films are shown in Fig. 1. The well resolved sharp peaks indicate that the samples are crystallized into the anatase phase which was stable even after doping, implying that the doping with Sr has no effect on the phase structure of TiO₂. Kumaresan *et al.*²³ have reported similar results in which Sr did not promote an anatase to rutile transformation. The average crystallite size of the crystalline anatase was calculated by the Scherrer equation:²⁸

$$
d = \frac{k\lambda}{B\cos\theta} \tag{1}
$$

where d is the crystallite size, k is a dimensionless shape factor which has a typical value of about 0.9, λ is the X-ray wavelength

Fig. 1 XRD patterns of the synthesized $TiO₂$ and Sr doped $TiO₂$ photoanodes.

of Cu (\sim 1.5406 Å), θ is the Bragg angle corresponding to the anatase (101) peak, and B is the line broadening at half the maximum intensity (FWHM). The average crystallite size of $TiO₂$ decreased with increasing concentration of Sr from 25.32 nm (undoped TiO₂) to 24.19 nm (50 ppm Sr doped TiO₂); the Sr dopant causes broadening of the (101) peak. According to Scherrer's formula, peak broadening is essentially associated with crystallite size and non-uniform strain (microstrain) due to shifts of atoms from their ideal position, which suggests that the dopant Sr distorts the TiO₂ lattice.²⁹ This may be attributed to the mismatch of the sizes of the dopant Sr^{2+} ion and host Ti^{4+} ions. The ionic radius of Sr^{2+} (1.18 Å) is higher than that of Ti^{4+} (0.60 Å) and so the insertion of larger ions into the lattice of smaller ions may enhance the possibility of local lattice distortions.²³ The reduction in average crystallite size with increasing concentration of Sr dopant has also been reported by A. Bakhshayesh et al.³⁰ Hamedani et al.²⁹ have reported that Sr^{2+} enters the $TiO₂$ lattice either in the interstitial sites or as a substitution for Ti^{4+} . The existence of larger sized Sr^{2+} in substitutional sites can cause volume compensating oxygen vacancies; such defect clusters would occur along different [hkl] directions in the $TiO₂$ lattice resulting in an alteration of the atomic distances³¹ and leading to distortion of the structure. Long et $al.^{32}$ reported that the insertion of foreign atoms changes the crystallization degree of anatase and the number of oxygen vacancies (crystal defects) due to the difference in chemical states and ionic radii between the Ti host and the

Fig. 2 SEM images displaying the surface morphologies of undoped photoanode (A) and the Sr doped $TiO₂$ photoanode (B); SEM image showing the cross section morphology of the films (C).

doping guest. The XRD peaks corresponding to the Sr dopant are not observed which may be due to its low doping concentration.

The surface morphologies of the pure and Sr doped (50 ppm) $TiO₂$ films are illustrated in Fig. 2(A) and (B), respectively. The morphology of both samples is highly crystalline which is in good agreement with the XRD results. It can also be seen from the SEM images that the photoelectrodes have typical porous structures. The average size of the nanoparticles is in the range of 20–30 nm. The cross section morphology of the films is provided in Fig. $2(c)$. The thickness of the films measured from SEM images is found to be around (12 μ m \pm 0.5).

The results of BET specific surface area values for doped and undoped samples are listed in Table 1. All the samples possess quite high specific surface area values, ranging from about 60 to 80 m² g^{-1} . The mean pore size diameter calculated by the BJH method is around 16–24 nm for all of the samples. A clear correlation exists among the various morphological parameters. The Sr doped $TiO₂$ photoanodes display higher pore size diameters, which increase up to 50 ppm of dopant, indicating that the doped samples may be more efficient compared to the undoped one with respect to dye loading. Additionally the measurements of pore size diameter show that 50 ppm doped samples have the most uniform structure, which might be attributed to their porous morphology. These parameters can influence the absorption capability of the photoanodes. Fig. 3 shows the UV-visible absorption spectra of undoped and Sr doped TiO₂ films. The absorption curve of Sr doped (50 ppm) $TiO₂$ film is red shifted relative to the undoped $TiO₂$ film. The red shift of the absorption edge suggests a reduction of the

Fig. 3 UV-visible absorption spectra of (a) pure $TiO₂$ and (b) Sr (50 ppm) doped TiO₂ photoanodes.

Fig. 4 Plots of $(\alpha h\nu)^{1/2}$ vs. photon energy of (a) pure TiO₂ and (b) Sr (50 ppm) doped TiO₂ photoanodes.

energy band gap. The Tauc model³³ was employed to determine the optical band gap energy using the following equation:

$$
\alpha h\nu = A(h\nu - E_{g})^{r}
$$
 (2)

where hv is the photon energy, E_g is the optical band gap, A is a constant, r is equal to 2 for allowed indirect optical transitions and α is the absorption coefficient. The measured indirect band gaps of the undoped and Sr (50 ppm) doped $TiO₂$ samples (Fig. 4) are 3.14 eV and 3.05 eV respectively. The reduction in the band gap can be attributed to the insertion of Sr into the $TiO₂$ lattice. Since the lower edge of the CB is made up of $Ti⁴⁺$ 3d bands, the substitution of Ti^{4+} with the Sr cation is expected to affect the CB structure. Bakhshayesh and Bakhshayesh³⁴ reported that the reduction in the energy band gap of strontium doped and co-doped $TiO₂$ nanoparticles is due to a modification of the conduction band. Naraginti et al.³⁵ also suggested that the effect of Sr on the electronic energy levels would be near to the conduction band edge causing an energy band gap reduction. Puper

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The adsorbed amount of dye for each film was determined by UV-vis absorption measurements. UV-vis absorption spectra of the desorbed dye from $TiO₂$ films measured in NaOH solution are shown in Fig. 5. It can be noted that the 50 ppm Sr doped $TiO₂$ film has the strongest dye absorption peak around 340– 550 nm, indicating the higher dye loading in this film compared with that of the pure $TiO₂$, 20 ppm, and 80 ppm films. The variation in pore volume and pore size diameter can be directly

Fig. 5 Absorption spectra of the dye N719 desorbed from the pure $TiO₂$ and Sr doped $TiO₂$ films.

Fig. 6 (a) J–V curve characteristics of DSSCs based on the undoped and Sr doped $TiO₂$ photoanodes under 1 Sun illumination; (b-d) variations of photovoltaic parameters of DSSCs for different doping amounts.

correlated to dye loading. The high dye loading exhibited by the 50 ppm Sr doped $TiO₂$ film can be attributed to its bigger pore volume and pore size.

XPS core level spectra of the undoped and doped $TiO₂$ nanoparticles for Sr are shown in the ESI [Fig. 1(a)–(e)]. \dagger It is difficult to find Sr in the Sr3d, Sr3s, and Sr3p regions as Sr is at ppm range. It is also difficult to identify the peaks corresponding to Sr4p and Sr4s from the regions of O2s and Ti3p as the peaks of Sr are superimposed by O and Ti peaks, respectively. However, it is found that peaks related to the O2s and Ti3p are shifted to higher binding energies with doping of up to 50 ppm Sr, and returned to lower binding energies for 80 ppm Sr which indicates an influence of the incorporated Sr dopant.

Fig. 6(a) represents the J–V characteristics of DSSCs of undoped and Sr doped TiO₂ photoanodes. The photovoltaic parameters including $V_{\text{oc}}, J_{\text{sc}}$, fill factor (FF), and PCE are listed in Table 2. Compared with the pure TiO₂, the Sr doped TiO₂ photoanodes showed better photovoltaic performances. A maximum PCE of 7.88% was obtained for the 50 ppm Sr doped $TiO₂$ based DSSC which is an improvement of 12.73% relative to that of the DSSC based on the pure $TiO₂$ photoanode. Fig. 6(b) shows the varying PCEs of the DSSCs of undoped and doped $TiO₂$ films. A significant improvement in the J_{sc} values was observed for DSSCs of TiO₂ nanoparticle electrodes doped with 20 or 50 ppm Sr. The $J_{\rm sc}$ of the DSSC is increased from 16.37 mA cm^{-2} (undoped TiO₂) to a maximum value of 17.43 mA cm⁻² for the 50 ppm Sr doped TiO₂ cell (Fig. 6(c)). This enhancement in

Table 2 Performance of DSSCs based on pure $TiO₂$ and Sr doped $TiO₂$ photoanodes

Doping amount (ppm)	$J_{\rm sc}$ (mA cm ⁻²)	$V_{\rm oc}$ (V)	PCE $(\%)$	FF(%)
0	16.37	0.683	6.99	0.62
20	16.77	0.708	7.11	0.59
50	17.43	0.728	7.88	0.62
80	14.16	0.724	6.43	0.62

Scheme 1 Equivalent circuit model of DSSCs. R_1 : serial resistance. R_2 : charge-transfer resistance of the FTO/TiO₂ and counter electrode/ electrolyte interfaces. CPE_1 : constant phase element of the FTO/TiO₂ and counter electrode/electrolyte interfaces. R_3 : electron transfer in TiO₂/dye/electrolyte interfaces. CPE₂: constant phase element of TiO₂/dye/electrolyte interfaces.

 $J_{\rm sc}$ is one of the reasons for improved efficiency.³⁶ Fig. 6(d) illustrates the variation of V_{oc} with different concentrations of dopant. The value of V_{oc} increased from 0.683 V for the pure $TiO₂$ cell to 0.728 V for the 50 ppm Sr doped cell, and then decreased to 0.724 V for the 80 ppm Sr doped cell. The simultaneous improvement of $J_{\rm sc}$ and $V_{\rm oc}$ values has been reported by many researchers.^{24,30,34}

The improvement in $J_{\rm sc}$ is due to both the narrowed band gap of the 50 ppm Sr doped $TiO₂$ that facilitates the better photoexcitation of the semiconductor, and the increased dye absorption. The efficient photoexcitation of $TiO₂$ and enhanced photo-injection contributes to the higher electron density. Furthermore, the introduction of Sr^{2+} leads to the generation of oxygen vacancies, as expressed by the following equation:³⁷

$$
Sr^{2+} + TiO2 \rightarrow Sr''Ti + 2VO
$$

These oxygen vacancy lattice defects, resulting from the substitution of Sr^{2+} in the sites of Ti^{4+} , can trap photo-generated holes, elongating the life of the photo-excited electrons and holes and thereby increasing J_{sc} ^{23,29,30,34} The life times of the photon excited charges were measured using EIS studies and are presented in the next section. The increase in V_{oc} for Sr doped TiO₂ samples up to 50 ppm is due to the enhancement in the number of electrons being injected and/or the suppression of recombination of injected electrons. The substitution of $Ti⁴⁺$ ions by Sr^{2+} leads to the distortion of TiO₆ octahedra and the introduction of oxygen vacancies thus generating dipole moments as well as internal polarization fields in the structure which facilitate the better charge separation efficiency of photogenerated electrons and holes³⁸ and decrease the recombination probability.³⁹ All of the above reasons are beneficial for a higher V_{oc} .

EIS was carried out in the frequency range of 0.1 to 10^5 Hz to investigate the effect of Sr doping on the charge transport

Table 3 EIS parameters of the DSSCs determined by fitting the experimental data to the equivalent circuit model

Electrodes (ppm)	R_{1}	R_{2}	$R_{\rm{2}}$	$f_{\rm max}$	τ_e (ms)
$\bf{0}$	19.48	3.227	16.642	13.803	11.533
20	22.49	1.751	16.882	11.220	14.18
50	21.80	1.737	17.681	7.413	21.47
80	22.53	2.239	19.129	9.120	17.45

Fig. 7 (a) EIS of DSSCs based on the undoped and Sr doped TiO₂ photoanodes under 1 Sun illumination at the applied bias of V_{occ} (b) Bode plots of DSSCs based on pure TiO₂ and TiO₂ doped with different amounts of Sr.

properties of the DSSCs. Based on the theoretical analysis of charge transport, the experimental data were fitted to the equivalent circuit model of the DSSCs which is given in Scheme 1. The EIS parameters of the DSSCs determined by tting the experimental data to the equivalent circuit model are given in Table 3. EIS plots (Fig. 7(a)) of the cells of doped and undoped TiO₂ taken at the applied bias of V_{oc} under one Sun illumination contain two semicircles. The smaller semicircle in the high frequency region is attributed to the charge transfer resistance $(R₂)$ at the two respective interfaces (electrolyte/Pt counter electrode) and $(FTO/TIO₂)$ and the larger semicircle in the low frequency region is mainly related to the charge recombination resistance R_3 across the TiO₂/electrolyte interface with a partial contribution from electron transport and accumulation in $TiO₂$ photoanodes.³⁹

The Nyquist plots show that the resistance related to electron recombination (R_3) increases with Sr content. The R_3 values are 16.642 Ω , 16.882 Ω , 17.681 Ω , 19.129 Ω for the undoped and 20 ppm Sr, 50 ppm Sr and 80 ppm Sr doped $TiO₂$ based cells, respectively. The higher values of R_3 indicate reduced electron recombination in Sr doped electrodes.⁴⁰ The life time (τ_e) of the photoelectrons is estimated using the relation:⁴¹

$$
\tau_{\rm e} = \frac{1}{2\pi f_{\rm max}}\tag{3}
$$

where f_{max} is the characteristic peak frequency value of the semicircle at lower frequency in the Bode plots (Fig. 7(b)). The electron life time increased with Sr doping up to 50 ppm. The measured life time of electrons for the undoped $TiO₂$ cell is 11.533 ms, and for 20 ppm Sr, 50 ppm Sr and 80 ppm Sr doped $TiO₂$ based cells, the life times are 14.18 ms, 21.47 ms and 17.45 ms respectively. These prolonged electron life times of doped $TiO₂$ nanoparticles indicate the suppression of the recombination rate and thus an increase in V_{oc} . This can be attributed to the reduction in the band gap as well as the lattice distortions that tend to accumulate variable oxygen vacancies so as to trap the photo-generated holes, extending the life of photo-excited electrons and holes³⁸ which results in better electron transport in the cells of doped $TiO₂$ particles. From the present investigations we infer that the DSSC of 50 ppm Sr doped $TiO₂$ nanoparticles exhibit optimum performance which will be beneficial for future applications. With this knowledge it is expected that Sr doped TiO₂ mesoporous electrodes can also be employed for other organic photovoltaic cell applications.

4. Conclusions

The present work provides a characterization of the effect of dopant (at very low concentrations) on the structural and electronic properties of $TiO₂$ nanocrystalline photoanodes for DSSC applications, and describes significant improvements in the performance of DSSCs. XRD and SEM studies reveal the formation of lattice distortions and crystal defects introduced by Sr insertion. Moreover, Sr doping leads to a reduction in the energy band gap of $TiO₂$ which plays an essential role in enhancing the performance parameters of the devices. The dye adsorption is improved by doping as a consequence of increased pore volume and pore diameter. DSSCs fabricated using a series of Sr doped TiO₂ photoanodes, show an overall conversion efficiency of 7.88% at 50 ppm Sr doping, which is 12.73% higher than that of cells made of pure $TiO₂$. In addition, the values of $J_{\rm sc}$ and $V_{\rm oc}$ of Sr doped TiO₂ photoanodes increase simultaneously with increasing concentration of Sr dopant up to 50 ppm. Recombination of charges is effectively suppressed by doping $TiO₂$ with Sr. The highest electron life time is achieved for 50 ppm Sr doped TiO₂. Thus it is reasonable to infer that the Sr doped TiO₂ may be developed as a promising material for future photo-conversion energy devices.

Acknowledgements

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